

CMOS pixel sensors for high precision vertex detectors

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IPHC-Strasbourg

- Physics motivations.
- CMOS principle of operation and performances.
- MIMOSA-26 and its applications.
- System integration.
- Developments.
- Summary and conclusions.

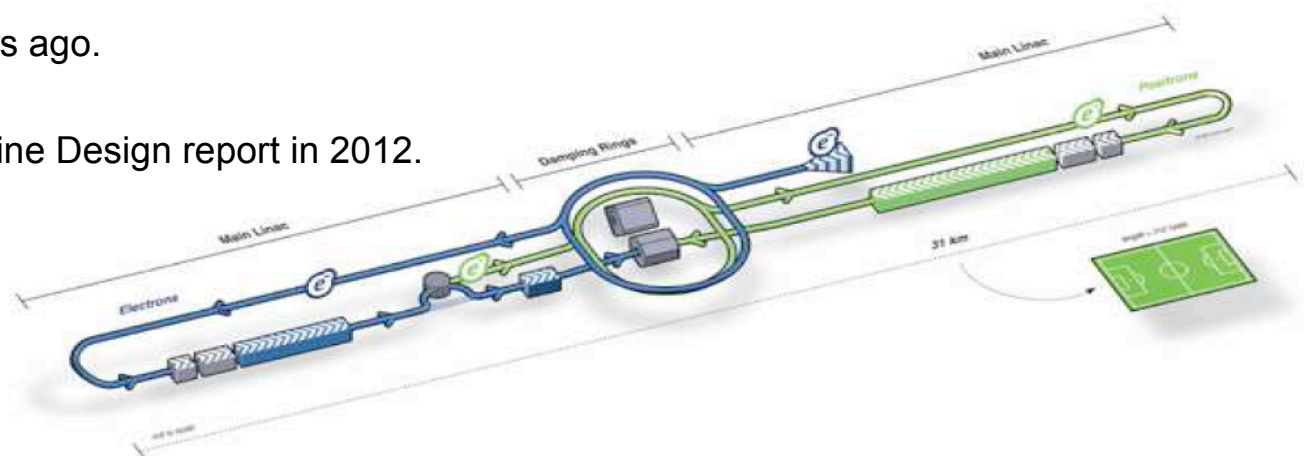
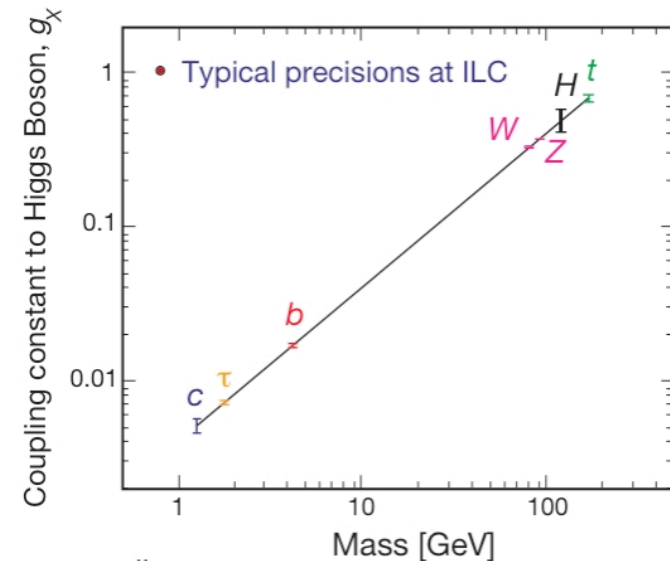
The International Linear Collider

Goals

- Higgs physics: quantum numbers, couplings, rare decays.
- New particles production.
- Extended sensitivity via loop effects.

$e^+ e^-$ linear collider

- Clean initial and final state.
- (Relatively) low background.
- Center of mass energy up to ~ 1 TeV.
- Superconducting RF technology.
- ~ 31 km long.
- $L = 2 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$.
- R&D started more than 10 years ago.
- Physics after 2020.
- Next milestone: Detector Baseline Design report in 2012.



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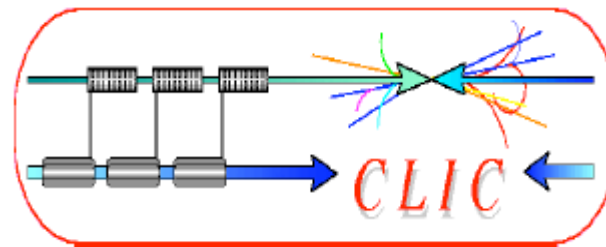
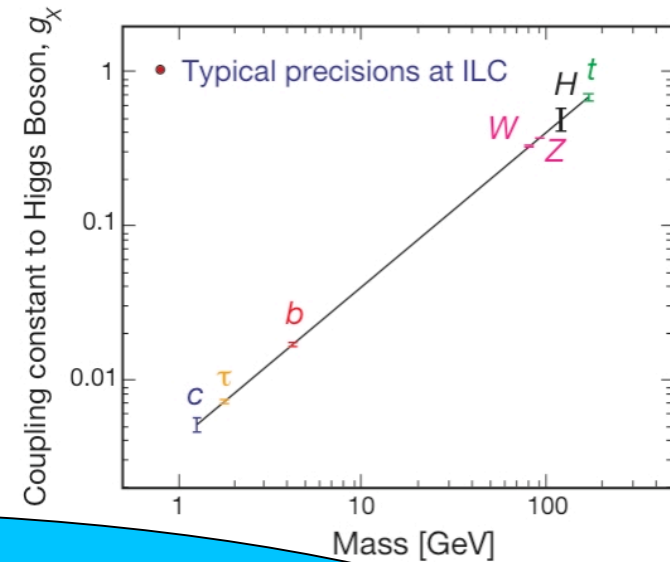
- Center of mass energy

- Superconducting

-

Compact Linear Collider (CLIC)

- New acceleration technique.
- Up to 3 TeV.
- Lot of R&D (machine and detector).



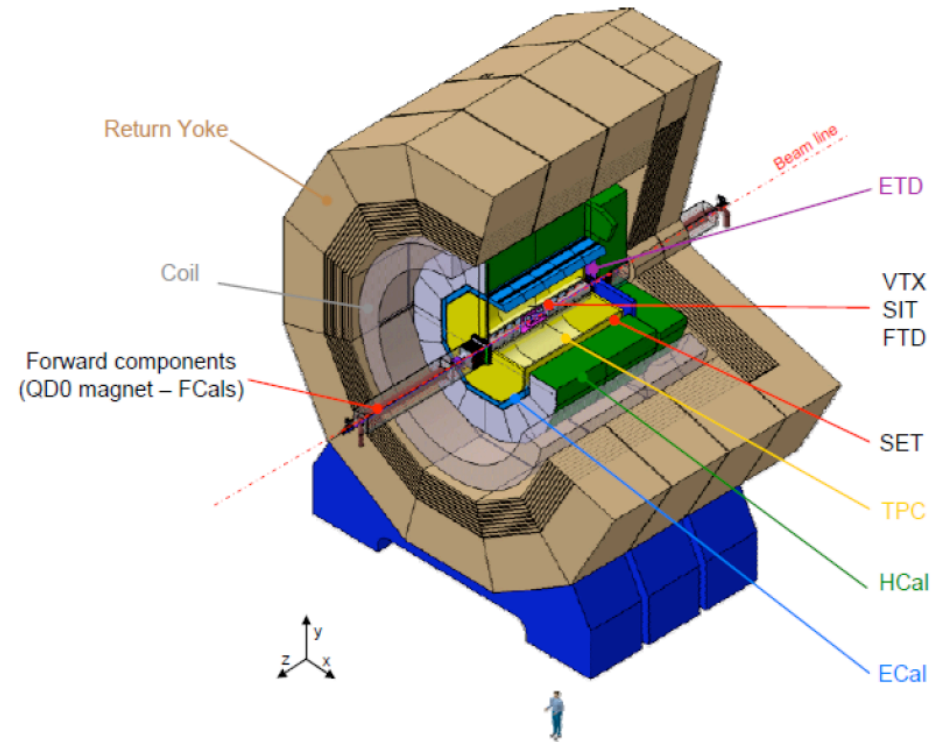
The ILD concept

Detector issues

- Particle flow
 - Granular calorimeter
 - “Light” tracker
- Excellent tracking and vertexing.
 - $\sigma_{IP} = 5\mu\text{m} \oplus 10\mu\text{m GeV} / p\sin^{3/2}\theta$
 - $\delta p/p = 5 \times 10^{-5}$.

Particle flow in a nutshell:

- reconstruction of single particles in a jet;
- charged particle with tracker;
- photons with ECAL;
- neutrons with HCAL.



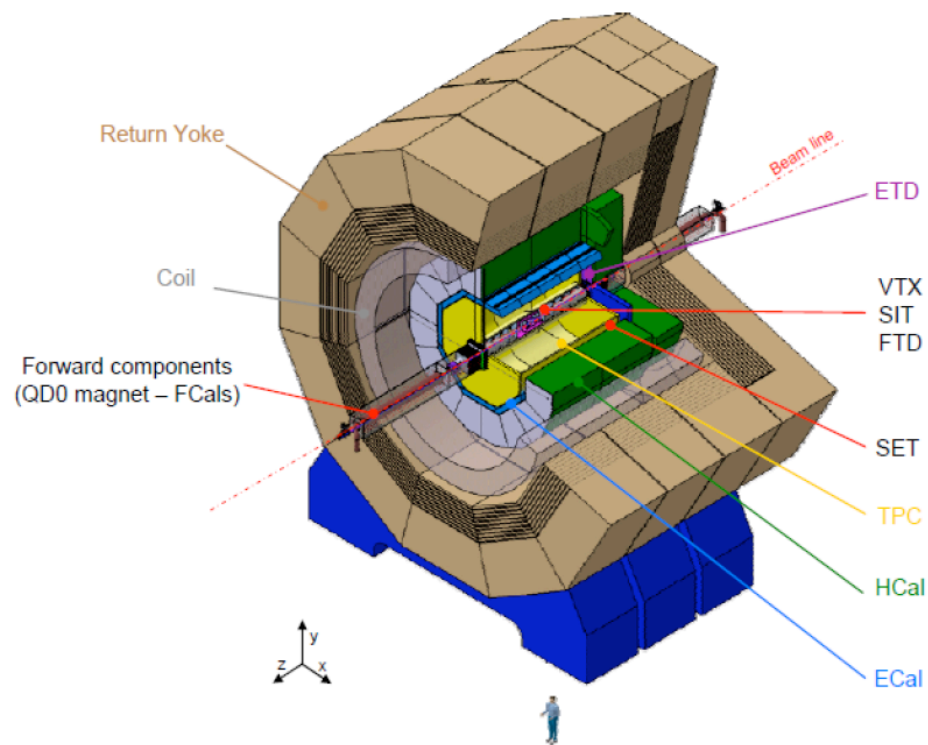
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SiD detector concept:
Si tracking system

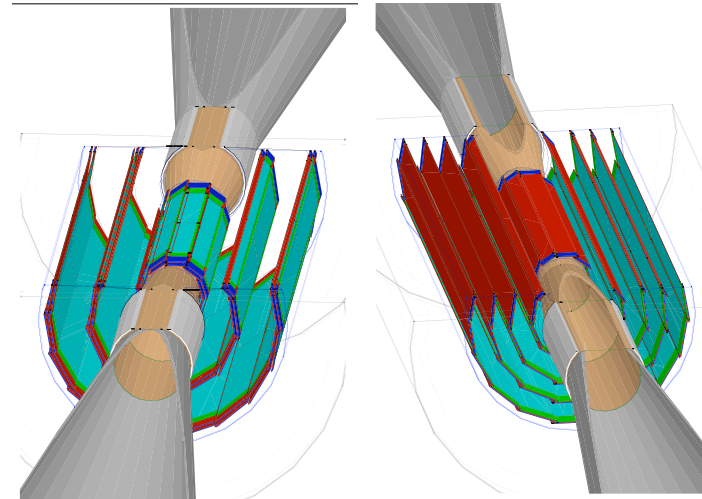
A vertex detector for the ILD - 1

Two alternative geometries

- 5 single-sided layers.
- 3 double-sided layers.

Sensor requirements

- Single point resolution $\sim 3\mu\text{m}$.
- Material budget $0.16/0.11\% X_0/\text{layer}$.
- Integration time $25 - 100 \mu\text{s}$.
- 16/15 mm inner radius.
- Radiation tolerance $\sim 0.3\text{MRad}$, few $10^{11}n_{\text{eq}}/\text{cm}^2$.
- $O(10^3)$ hit pixels/ $\text{cm}^2/10 \mu\text{s}$ on the inner layer.
- Averaged power dissipated $\ll 100 \text{ W}$.



A vertex detector for the ILD - 2

$$\sigma_{IP} = a \oplus b/p \sin^{3/2}\theta$$

<i>Accelerator</i>	<i>a (μm)</i>	<i>b (μm GeV)</i>
LEP	25	70
SLD	8	33
LHC	12	70
RHIC-II	13	19
ILC	< 5	< 10

a depends on the intrinsic resolution and inner radius

b depends on material budget

Fast, highly granular, light detector !

CMOS sensor principle

Signal collection

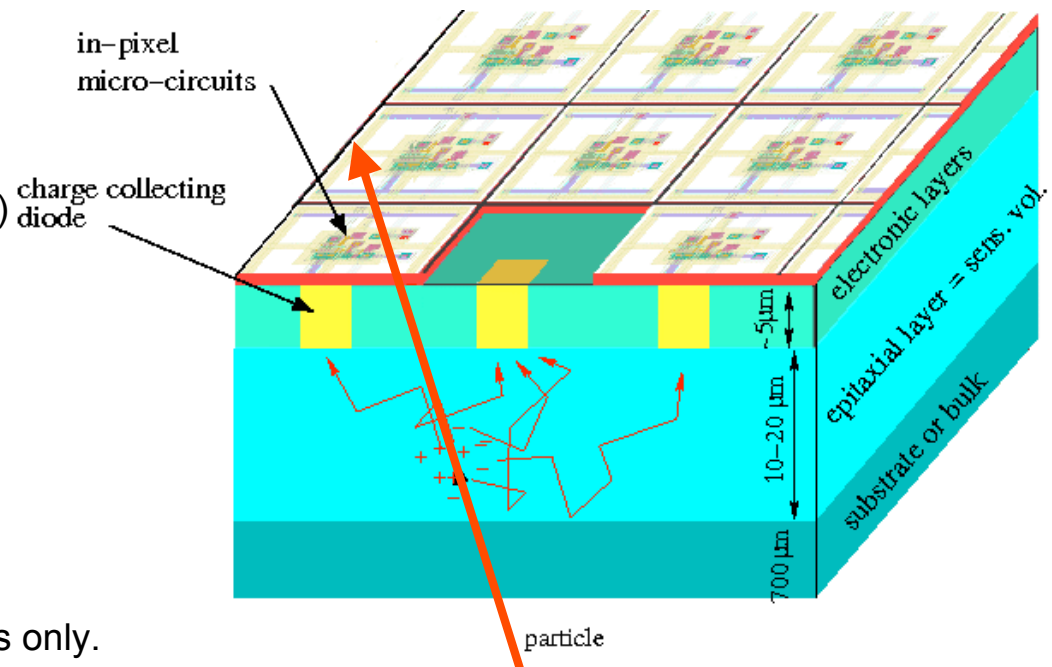
- Charges generated in epitaxial layer $\rightarrow \sim 1000 e^-$ for MIP.
- Charge carriers propagate thermally.
- In-pixel charge to signal conversion.

Advantages

- High granularity ($< 10 \mu\text{m}$ pitch).
- Thickness ($< 50 \mu\text{m}$).
- Integrated signal processing.
- Standard process (cost, prototyping, ...)

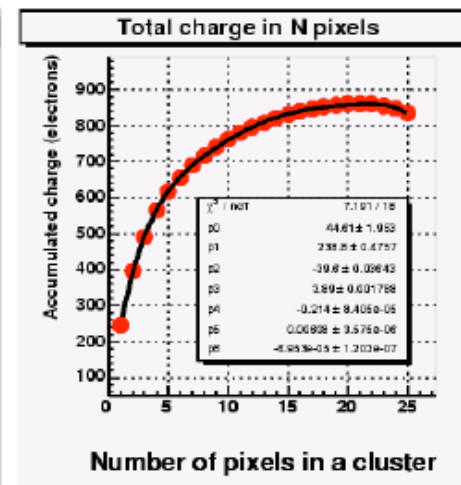
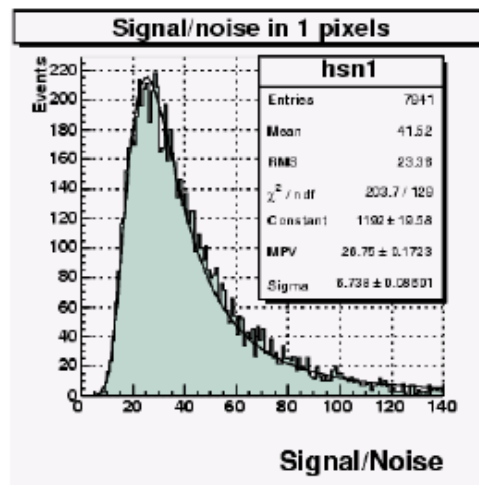
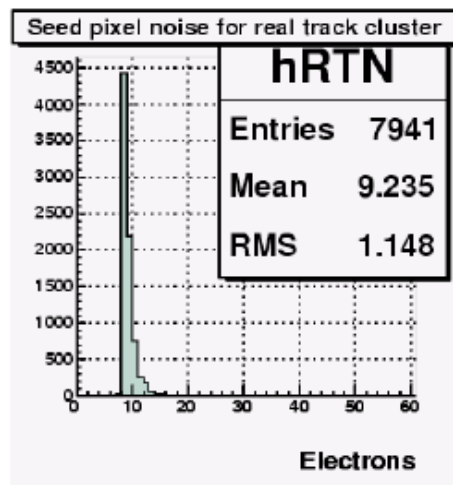
Issues

- Undepleted volume limitations .
 - radiation tolerance.
 - intrinsic speed.
- Small signal $O(100e^-)/\text{pixel}$.
- In-pixel μ -circuits with NMOS transistors only.



Basic performances

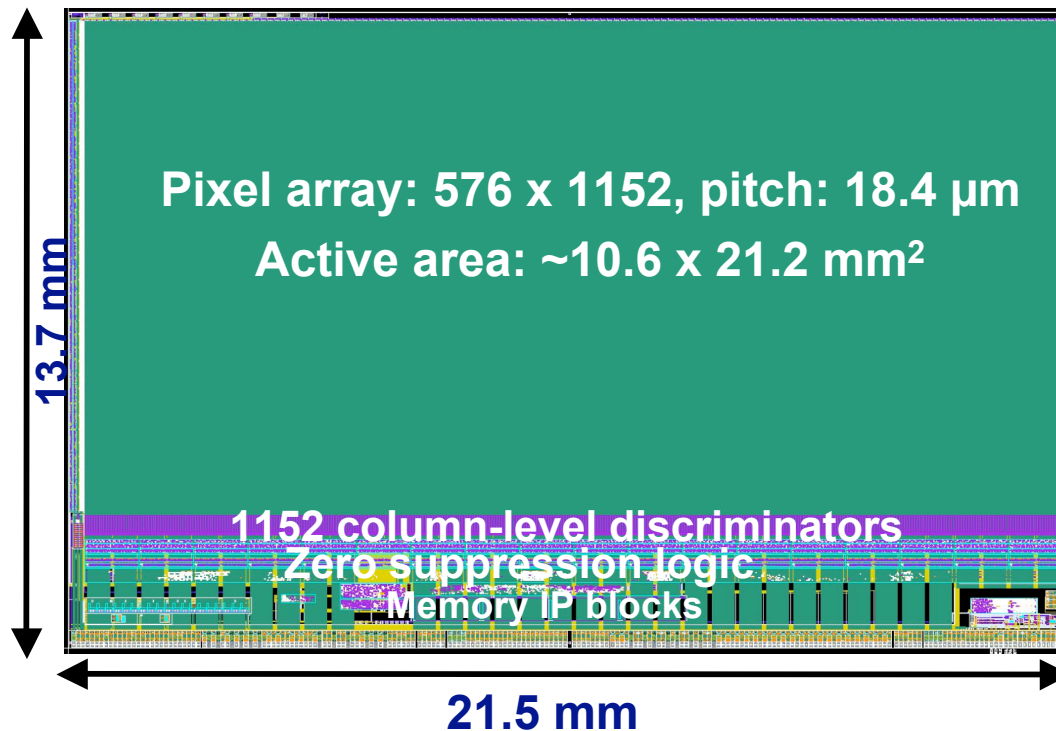
- More than 30 different sensors designed, fabricated and tested (lab & beam).
- Extensive use of $0.35\mu\text{m}$ CMOS technology.
- Room temperature operation.
- Noise $\sim 10\text{-}15e^-$.
- S/N $\sim 15\text{-}30$.
- Detection efficiency $\sim 100\%$ @ fake hit rate $O(10^{-4} - 10^{-5})$.
- Radiation tol. $> 1\text{MRad}$ and $10^{13}n_{\text{eq}}/\text{cm}^2$ with $10\mu\text{m}$ pitch ($2 \times 10^{12}n_{\text{eq}}/\text{cm}^2$ with $20\mu\text{m}$ pitch).
- Spatial resolution $1\text{-}5\mu\text{m}$ (pitch and charge-encoding dependent).
- Macroscopic sensors (Ex. MIMOSA-5: $1.7 \times 1.7\text{ mm}^2$, 10^6 pixels).
- Used in beam telescopes and VTX demonstrators (EUDET, TAPI, STAR, CBM).



Mimosa-26

Fast full scale sensors: ~10kFrame/s

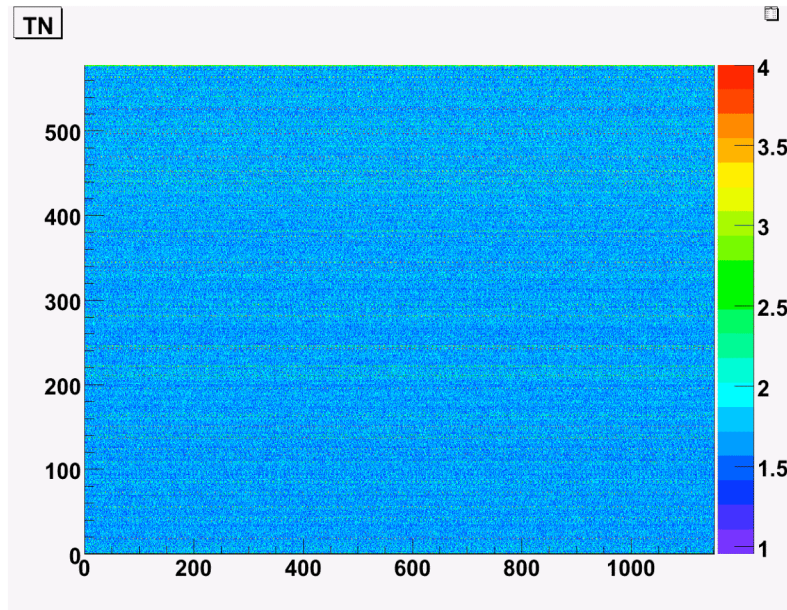
column parallel architecture + integrated zero-suppression
(prototyping with MIMOSA-22 for binary output + SUZE-01 for $\emptyset$)



- Active area ~2 cm^2 .
- 0.35 μm technology.
- Binary output (3.5 - 4 μm spatial resolution).
- In-pixel CDS + preamp.
- Column level discrimination.
- Power dissipated ~280 mW/cm^2 (rolling shutter).
- Integration time ~100 μs .

6 wafers x 77 sensors produced: fabrication yield ~90%

Laboratory tests



Analogue response for 8 different sensors:

- All pixels are alive.
- Noise is uniform across the sensitive area ($\sim 2\text{cm}^2$).
- Operated from 80 MHz (nominal) down to 20 MHz.
- Noise and CCE (from ^{55}Fe source) as expected (like MIMOSA-22).

Digital response for 21 different sensors:

- All discriminators are operational at nominal speed.
- Discriminator noise like MIMOSA-22.

Analogue + digital response:

- Total noise 0.7 mV ($\sim 12\text{-}13\text{ e}^- \text{ ENC}$) like MIMOSA-22.

Zero-suppression works as expected.

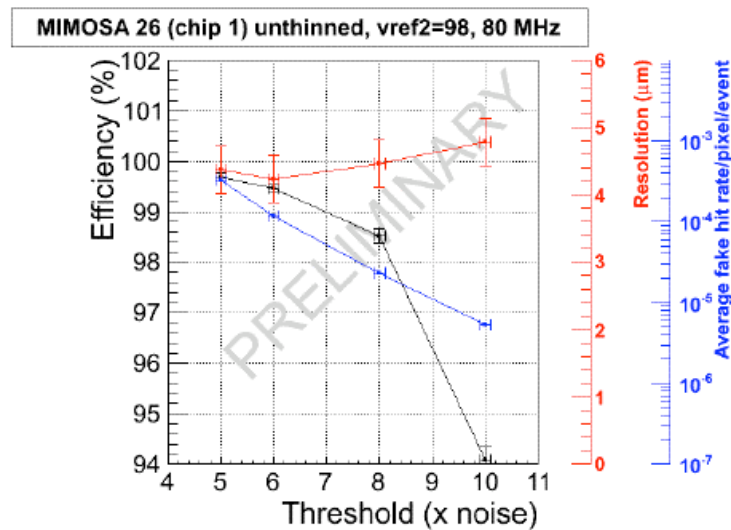
Full chain:

- Fake hit rate $O(10^{-4})$ @ 6N discr. threshold.
- Performances unchanged for $20^\circ < T < 40^\circ$

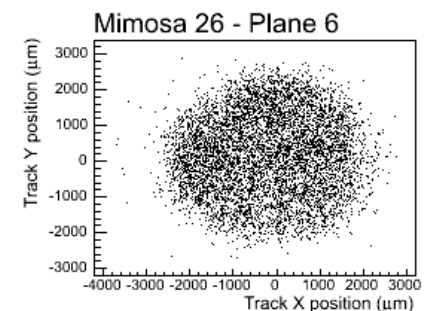
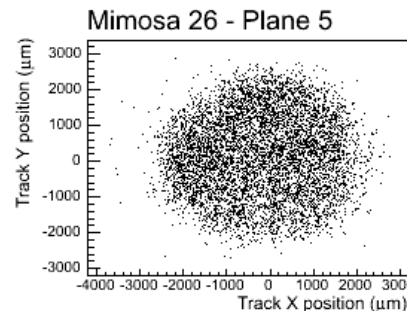
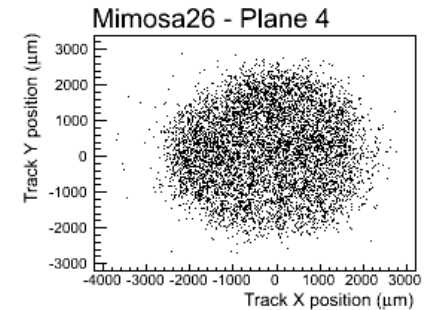
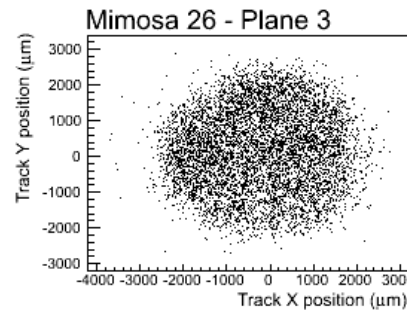
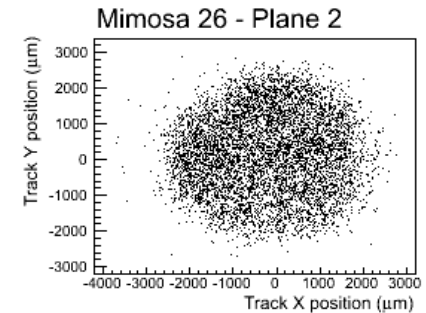
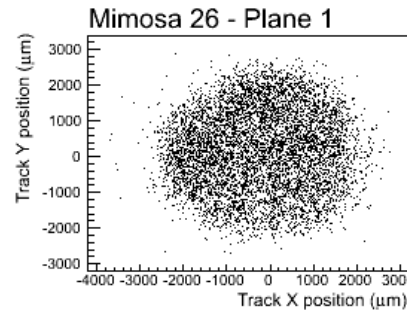
Array of 660,000 pixels coupled to 1152 discriminators works ~ as expected

Preliminary beam test results

- TAPI = IPHC-Strasbourg BT for MIMOSA development.
- Test @ CERN-SPS (120 GeV π^- beam).
- 6 MIMOSA-26 sensors running simultaneously at nominal speed (80 MHz).
- 3×10^6 triggers.



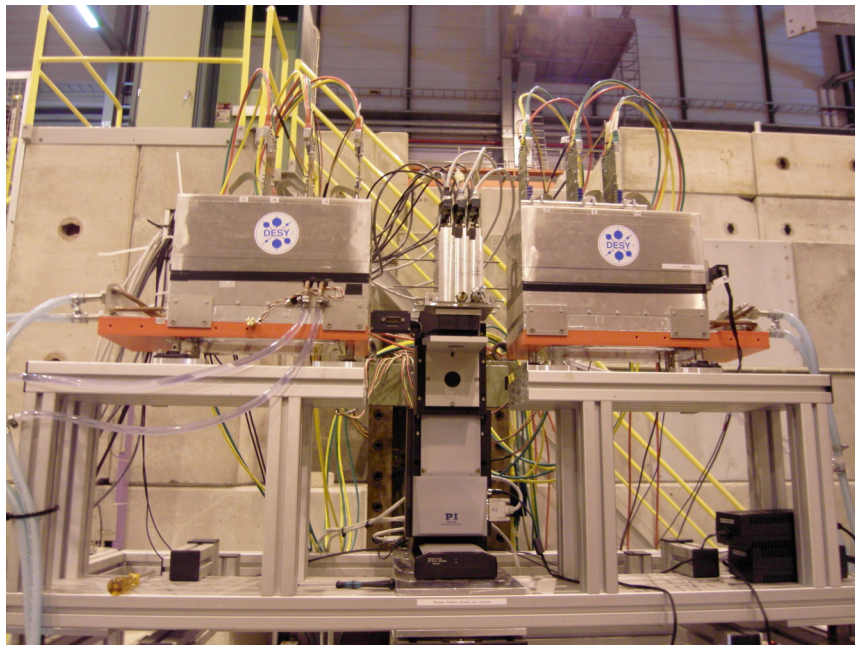
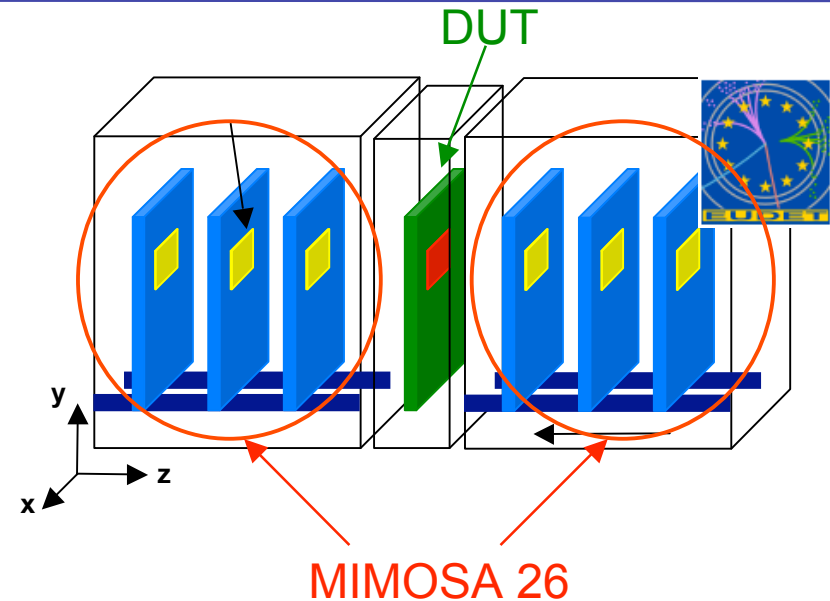
$\epsilon = 99.5 \pm 0.1$ (stat.) ± 0.3 (prel.) %
@ fake hit rate $O(10^{-4})$



EUDET beam telescope

Reference planes of EUDET Beam Telescope

- Supported by EU FP6.
- Infrastructure to support the ILC detector R&D.
- Specifications:
 - Extrapolated resolution $< 2 \mu\text{m}$.
 - Sensor area $\sim 2 \text{ cm}^2$.
 - Read-out speed $\sim 10 \text{ kframe/s}$.
 - Up to 10^6 hits/s/cm^2 .

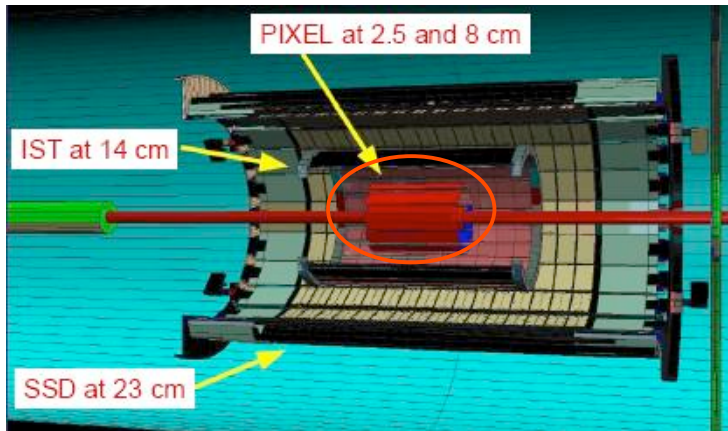


Commissioning @ CERN-SPS last year:

- BT completely equipped with MIMOSA-26.
- Largely used by ILC and non-ILC groups.

www.eudet.org

Mimosa-26 evolutions: STAR HFT



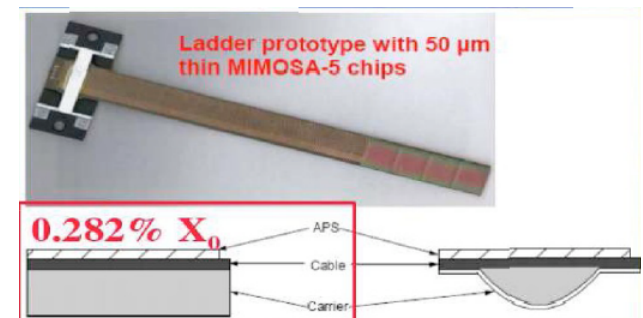
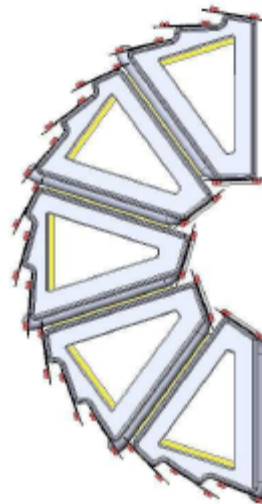
STAR @ RHIC Heavy Flavour Tracker

PHASE-1:

- no $\emptyset$
- 640 x 640 pixels (30 μm pitch);
- 640 μs integration time.
- 50 μm thin.
- 1/4 of the detector.

ULTIMATE:

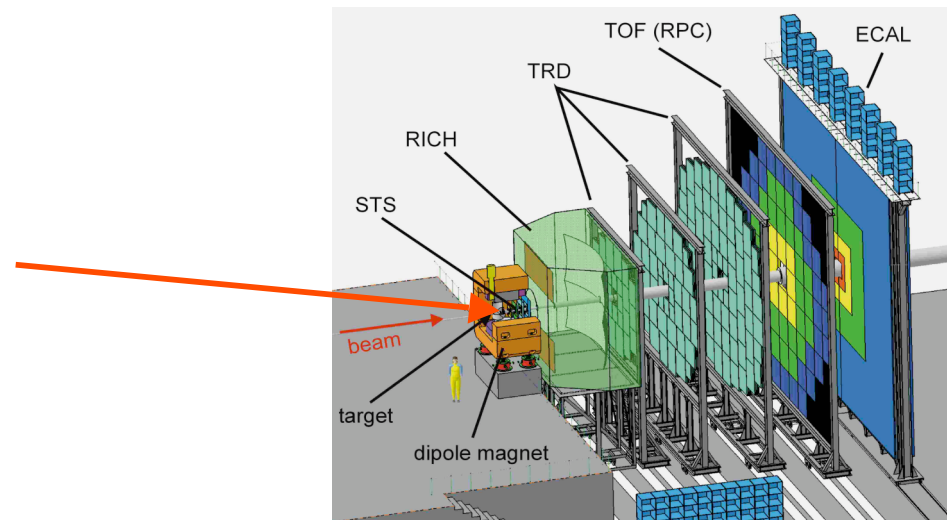
- MIMOSA-26 like.
- 1152 x 1024 pixels (18.4 μm pitch);
- 200 μs integration time.
- 50 μm thin.
- Improved radiation tolerance.
- First data in 2012



Mimosa-26 evolutions: CBM MVD

CBM @ FAIR Micro Vertex Detector

- Double sided readout.
- $0.18\ \mu\text{m}$ ($40 \rightarrow 20\ \mu\text{s}$ integration time).
- Improved radiation tolerance.
- Prototyping until 2012.



Interest expressed by the ALICE collaboration for the upgrade in view of sLHC

The ILD applications

Physics requirements

- single point resolution $\sim 3\mu\text{m}$.
- integration time 25 – 100 μs .
- $O(10^3)$ hit pixels/cm²/10 μs on the inner layer.
- ...

From 0.35 μm to ($<$)0.18 μm feature size:

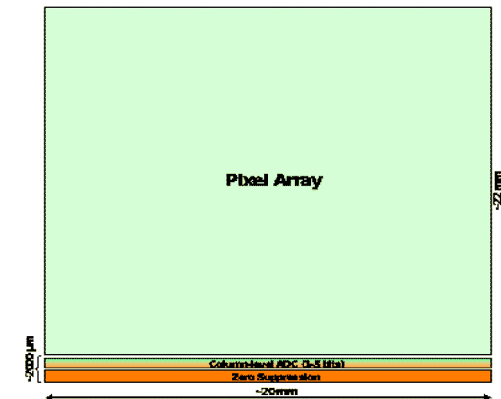
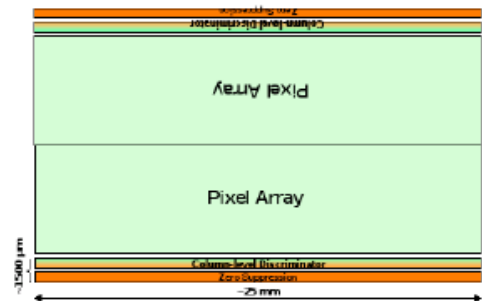
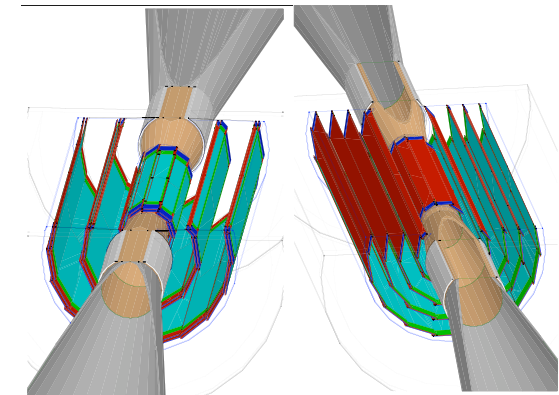
- improved clock frequency, more metal layers, more compact peripheral circuitry, ...

Extension for the outer VTX layers:

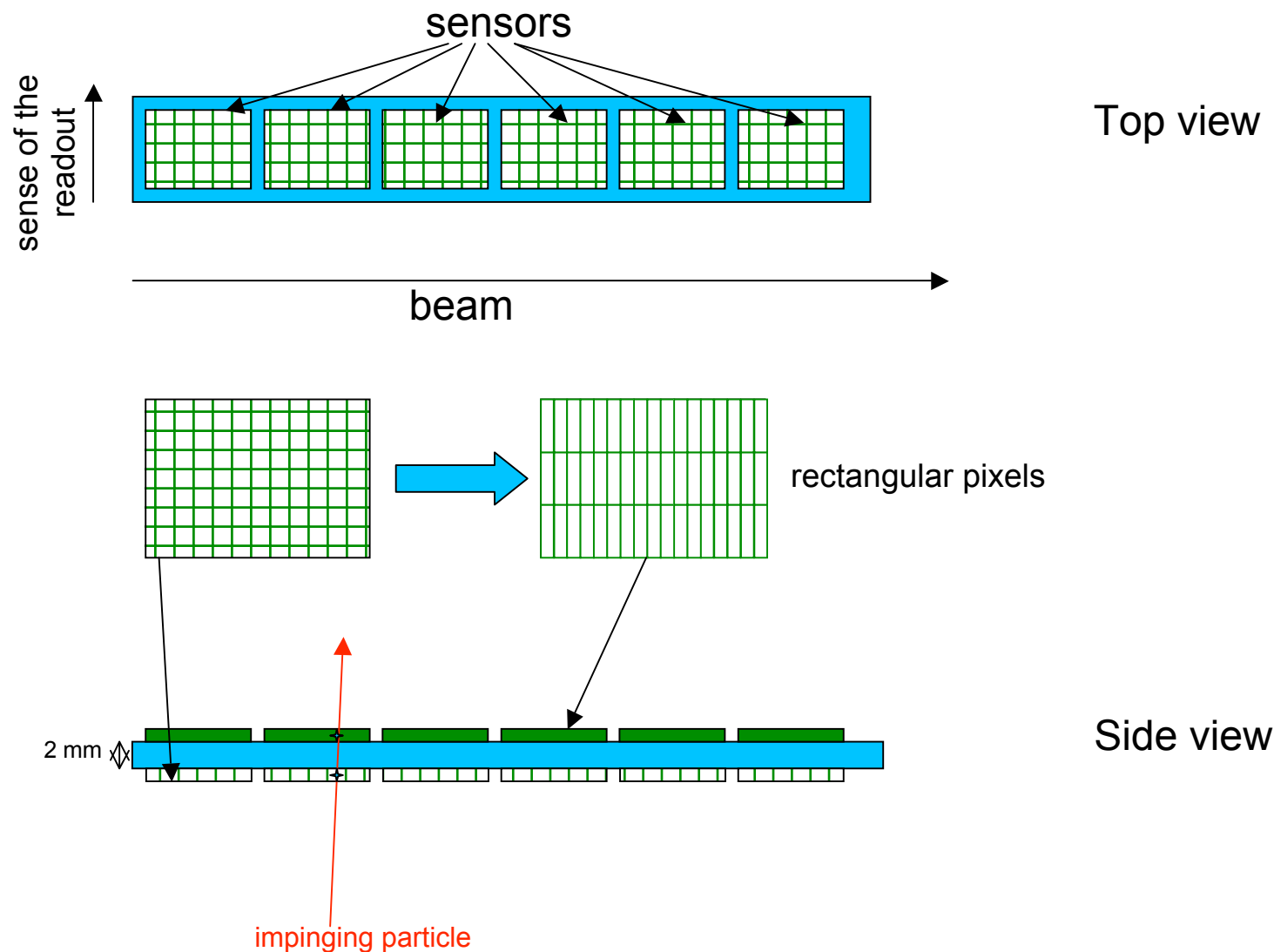
- $\sigma \sim 3\mu\text{m}$: 4-5 bits ADC and a $\sim 35\mu\text{m}$ pitch (r.o. $\sim 100\mu\text{s}$).

For the inner layers:

- $\sim 15\mu\text{m}$ pitch $\rightarrow$ binary readout.
- Double-sided r.o. $\rightarrow$ r.o. $\sim 50\mu\text{s}$.
- Smaller feature size $\rightarrow 35 - 40\mu\text{s}$.
- Double sided ladders $\rightarrow << 35\mu\text{s}$.

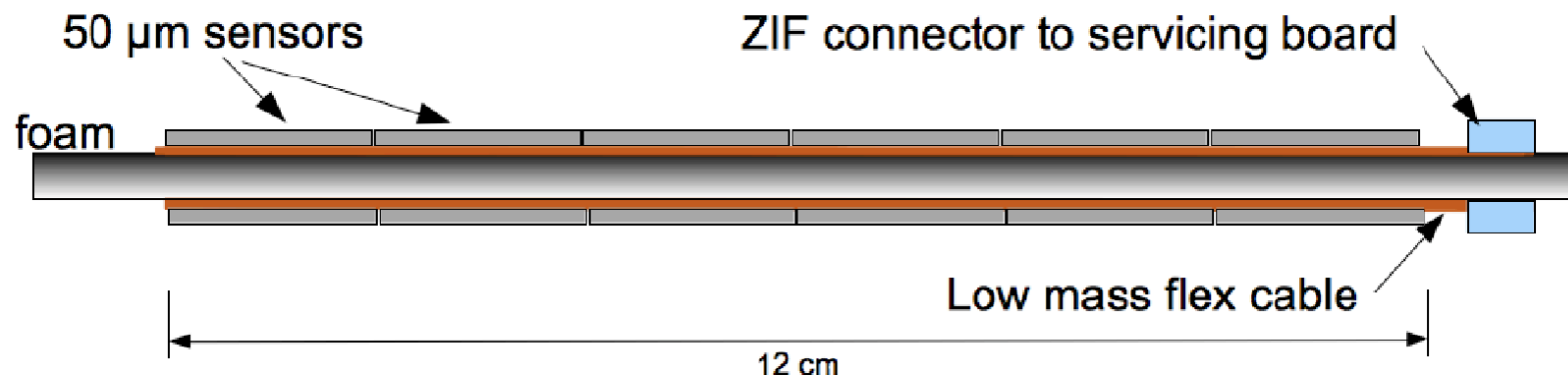


Improve time resolution with double sided structure



System integration: the PLUME project

- Pixel Ladder with **U**ltra-low **M**aterial **E**MBEDDING.
- Bristol - DESY - Oxford - Strasbourg (synergy with CBM-MVD).
- Double sided ladder equipped with 2x6 MIMOSA-26 (ILC DBD 2012).
- 0.2 - 0.3 % X_0 .
- Explore feasibility, performances and added value of double-sided ladders.
- Allows for improved time resolution (outer layer with longer and fewer pixels).
- Use of infrastructures foreseen in AIDA (FP7 project in preparation).



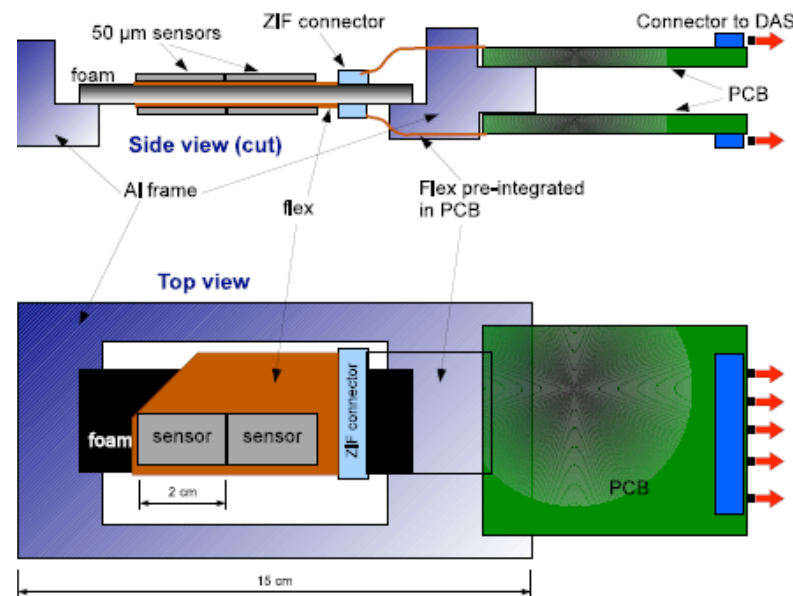
System integration: the PLUME project

2009

- 2 pairs of MIMOSA-20 sensors ($4 \times 1 \text{ cm}^2$, $50\mu\text{m}$ thin) mounted on flex cable + SiC support.
- Total material budget $\sim 0.5\% X_0$.
- Beam test at CERN-SPS in November.

2009 - 2012

- 2 x 6 MIMOSA-26 sensors ($12.5 \times 1 \text{ cm}^2$, $50\mu\text{m}$ thin) mounted on flex cable + SiC support.
- Total material budget $\sim 0.2\% X_0$.



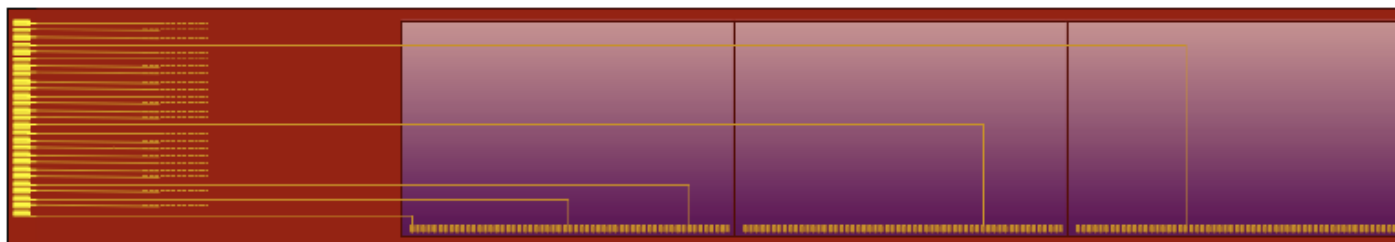
System integration: SERWIETE

- **SE**nsor **R**ow **W**rapped In **E**xtra-Thin **E**nvelope (HP 2 Project).
- Frankfurt – Darmstadt – Strasbourg.
- Sensors wrapped in thin polymerised film.
- $<0.15\%$ X_0 expected for sensor (35 μm thin) $\oplus$ flex $\oplus$ film (no mechanical support).
- May match cylindrical surfaces (beam pipe?).
- Proof of principle in 2012.
- First prototype by Spring (analog output, $\sim 4\text{ms}$)
- Second prototype by 2011 (digital output, $\sim 110\mu\text{s}$)

Proto 1 $\triangleright$ Spring 2010



Proto 2 $\triangleright$ Summer 2011



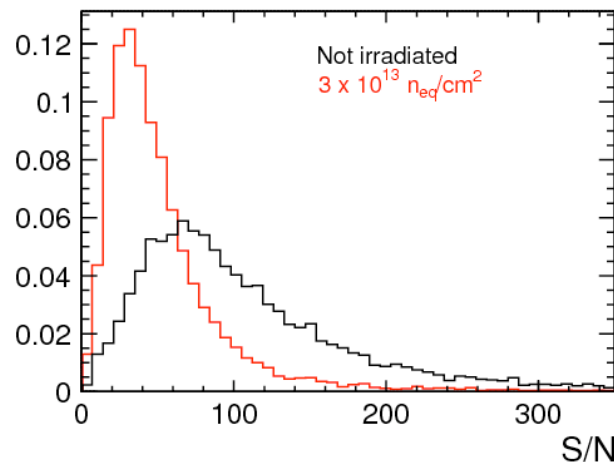
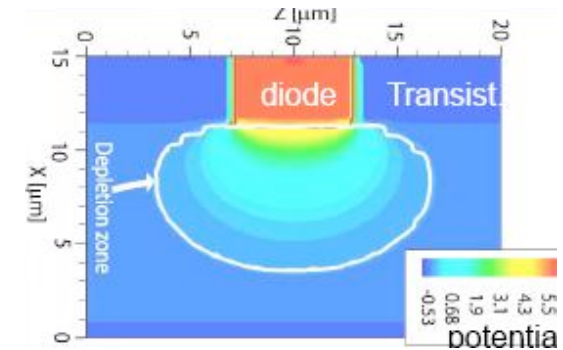
Further developments: high resistivity epi layer

High resistivity epitaxial layer ($O(10^3) \Omega \cdot \text{cm}$) $\Rightarrow$ depleted sensitive volume!

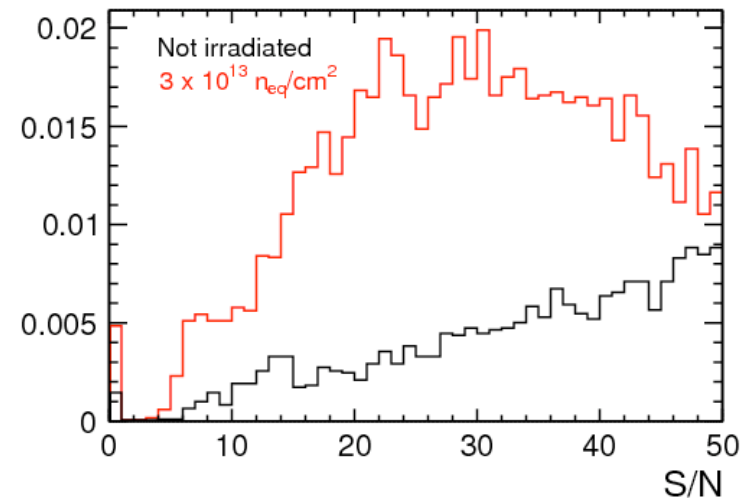
- $\Rightarrow$ Faster charge collection
- $\Rightarrow$ Shorter path length (improved tolerance to non-ionising radiation)
- $\Rightarrow$ Larger CCE (larger pitch possible without affecting the detection efficiency)

Exploratory sensor: MIMOSA-25 ($0.6 \mu\text{m}$ technology)

- Fabricated in 2008 and tested at CERN-SPS before and after irradiation.
- Cluster size $\sim 2 \times 2$ pixels (3×3 for low resistivity epi-layer).
- S/N ~ 60 for seed (20-25 for low resistivity epi-layer - ~ 30 @ $3 \cdot 10^{13} n_{\text{eq}}/\text{cm}^2$).
- $\varepsilon = 99.9\%$ (99.5% @ $3 \cdot 10^{13} n_{\text{eq}}/\text{cm}^2$).
- Improved tolerance to non-ionizing radiation (1-2 OoM).



ZOOM



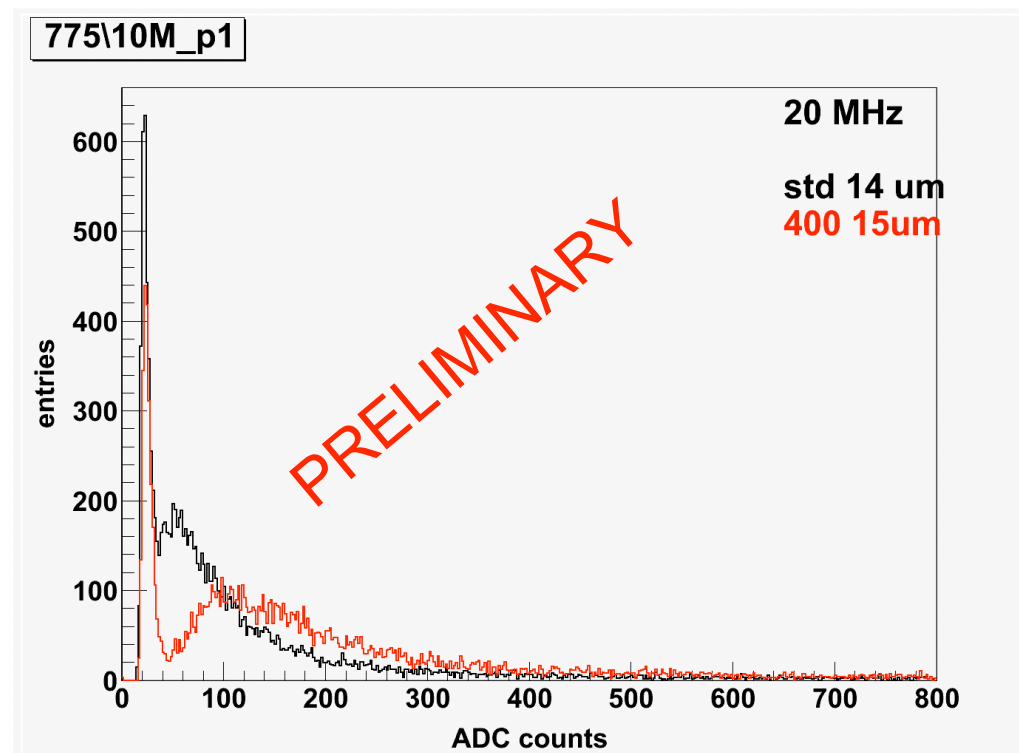
Also: VDSM technology under study in coll. with CERN for sLHC (LePIX) ($< 1 \mu\text{s}$)

MIMOSA-26 with high resistivity epi layer

NEW!

MIMOSA-26 high res.(400 $\Omega\cdot\text{cm}$) 0.35 μm presently under test (for STAR-HFT)

Preliminary lab test with Ru source (Analog test mode)



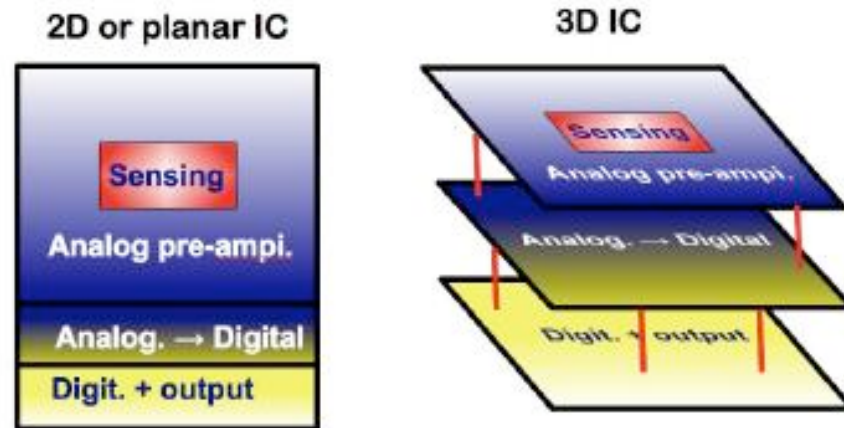
Further developments: 3D IT

Benefits:

- Increase integrated processing.
- 100% sensitive area.
- Select best process per layer task.

To be assessed:

- Material budget?
- Power dissipation?



Example

- Tier1: charge collection.
- Tier2: analog signal processing.
- Tier3: digital signal processing.
- Tier4: data transfer.

FNAL + IN2P3 + INFN + ... consortium (3DIC)
First chips (2-Tier 130nm technology) being fabricated

3D IT first try

2 Tiers sensor for delayed readout:

- ILC delayed readout.
- ro + discri+ time stamp + memory in each pixel.
- 12 μm pitch (reduce # hits/pixel/ro)

2 Tiers sensor to minimize power consumption:

- IPHC-IRFU
- Rolling-shutter in submatrices

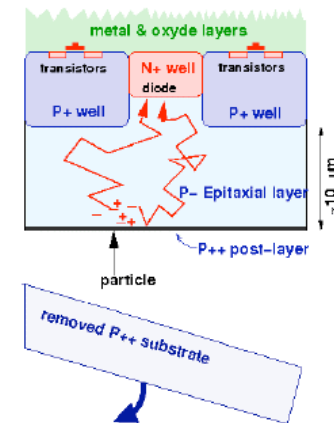
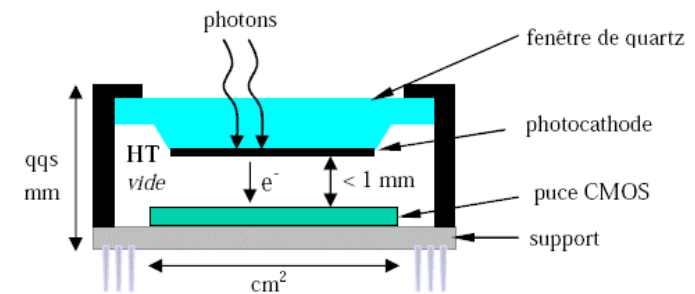
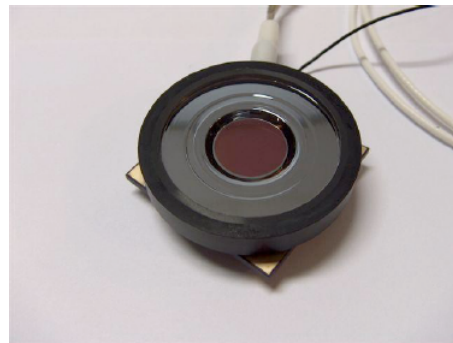
3 Tiers sensor:

- IPHC-INFN Padova/Bergamo
- 2 Tiers signal processing + 1 Tier detection (High res.)
- $\sim 1 \mu\text{s}$ readout

Other (non HEP) applications

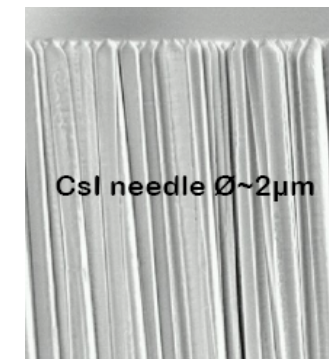
ebCMOS:

- IPHC-IPNL-PHOTONIS.
- Single (visible) photon detection.
- Fluorescence microscopes.



X-rays :

- Direct illumination below 10 keV
- Converter above 10keV (Columnar CsI crystals from Hammamatsu)
- Dosimetry, surgery camera, ...



Summary and future perspectives

Current CMOS sensors

- Mature technology for real scale applications.
- High resolution, very low material budget.

First full scale sensor with high read-out speed: MIMOSA-26.

- Binary output + integrated zero-suppression.
- Tested in laboratory and on beam.
- EUDET-BT, STAR-HFT, ALICE, CBM-MVD, ILD-VTX (option).

System integration studies started: PLUME, SERWIETE, → Material budget $O(0.1 \% X_0)$

New perspectives

Depleted sensitive volume:

- Technology prototyped with MIMOSA-25.
- MIMOSA-26 high res. under test.
- Expectations: fast charge collection and non ionizing radiation tolerance $> 10^{14} n_{eq}/cm^2$.

3D integration technique:

- 3 CAIRN prototypes being produced (low power, few μs r.o., delayed readout with timestamp).
- Heterogeneous chip (depleted sensitive volume).

More information on

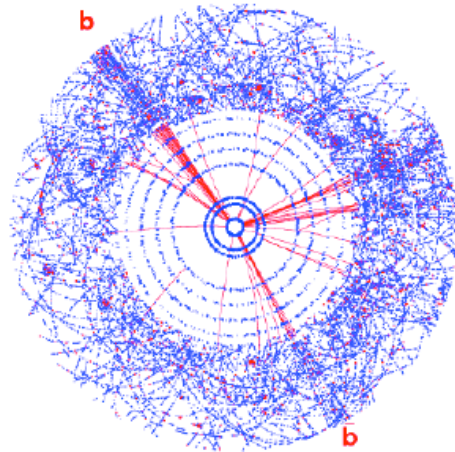
<http://www.iphc.cnrs.fr/-CMOS-ILC-.html>

Backup slides

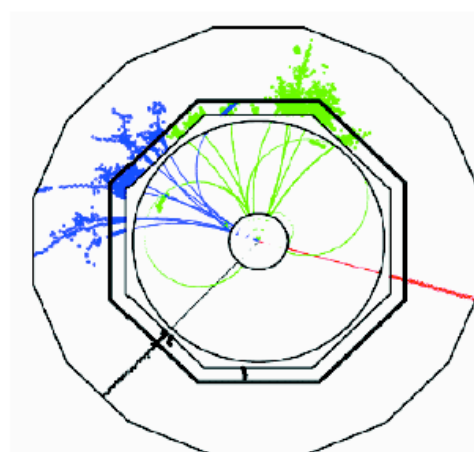
Calorimeter R&D for HEP detectors

The largest scale HEP detectors at (s)LHC and the future LC

The LHC $pp \rightarrow H + X$



The ILC $e^+e^- \rightarrow HZ$



★ At electron-positron the final state corresponds to the underlying physics interaction, e.g. above see $H \rightarrow b\bar{b}$ and $Z \rightarrow \mu^+\mu^-$ and nothing else...

High precision LC physics demands a high precision detector:

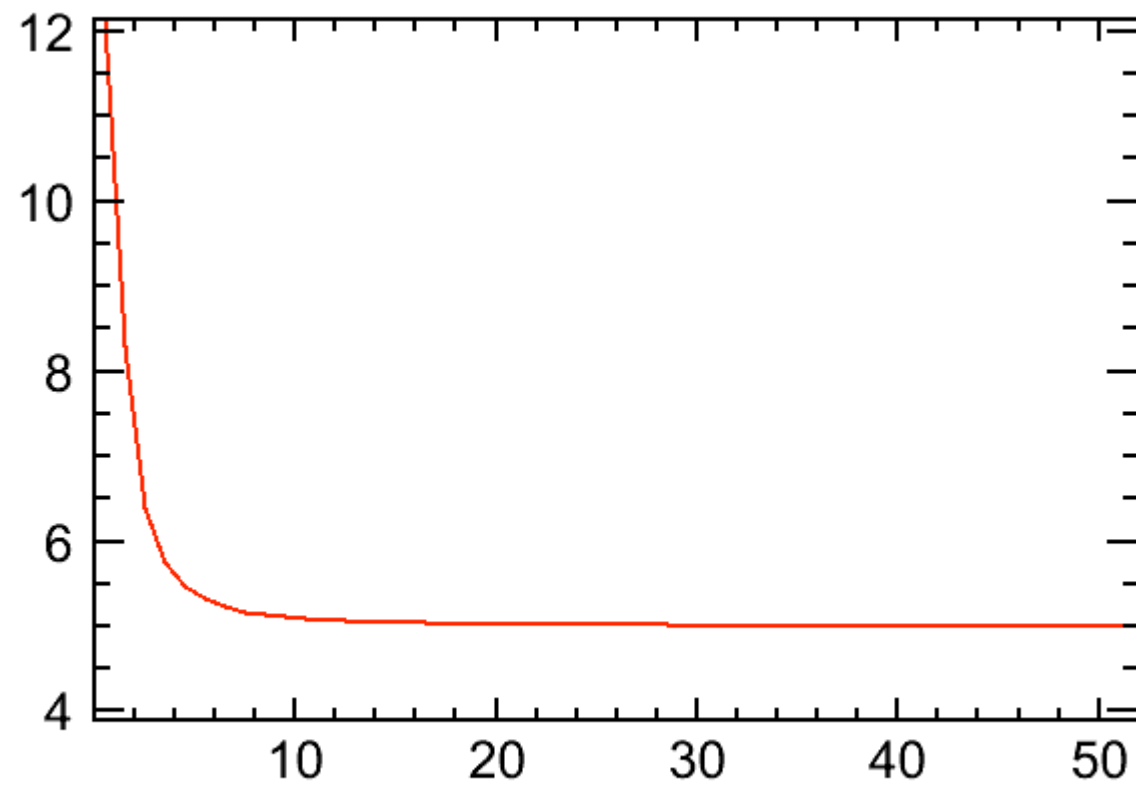
- high precision vertex (flavor tagging) and tracking (Higgs from di-lepton recoil mass)
- **precision calorimetry** (heavy bosons reconstruction from **di-jet** decay)
- **significant improvements** in the calo. system, in particular **in the HCAL**

15-20 Feb 2010

Erika Garutti - Calorimetry

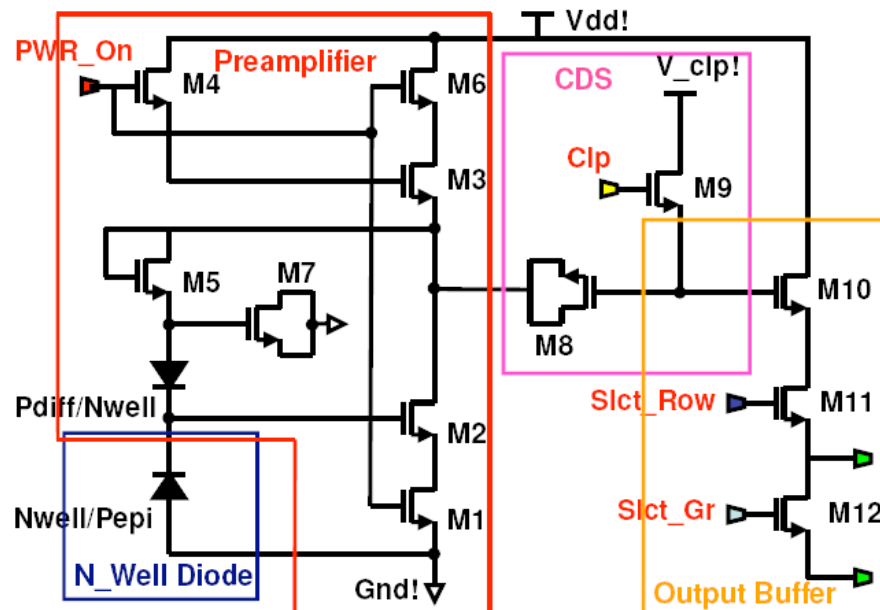
4/44

TMath::Sqrt(5^2+(10/x)^2)

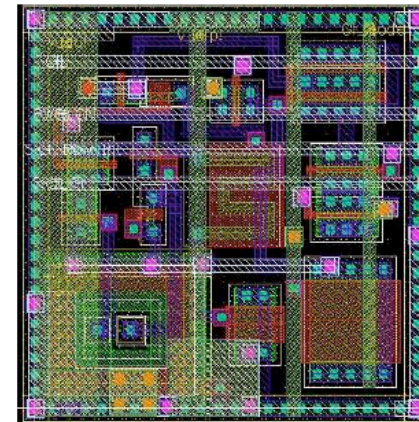


Readout Chain: Pixel

See Ref. A. Dorokhov et al., TWEPP-07 CERN-2007-007 proceeding pp. 423-427

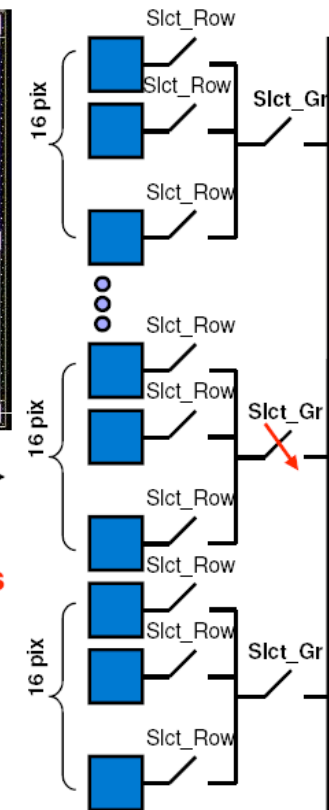


ONLY NMOS transistors can be used, since any additional N-well used to host PMOS transistors would compete for charge collection with the sensing N-well diode



18.4 μm

Readout = 16 CK cycles



1 (or 2) cm long!!!



- 4 digital control signals per row: *PWR_On*, *Slct_Row*, *Slct_Gr*, *Clp*
 - Slct_Row* (16CK), *PWR_On* (2x16CK), *Slct_Gr* (16x16CK): power activate signals
 - Clp*: signal for CDS (3CK)
- Power consumption: ~200 μW/pixel

Backup slides

Backup slides

Backup slides